

# **APPLICATION NOTE**

# TS912 : DRIVING A PIEZOELECTRIC CELL WITH A RAIL TO RAIL OP-AMP

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### INTRODUCTION

The TS912 is an input/output rail to rail dual CMOS operational amplifier. It is able to operate with low supply voltage (2.7V) and to drive low output loads (600 $\Omega$ ).

As an illustration of these features, the following note is describing the TS912 behaviour when driving a piezoelectric cell.

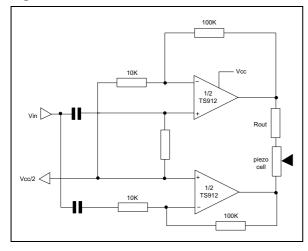
#### **APPLICATION CIRCUIT**

The TS912 is used in a single supply push-pull configuration as displayed below in figure1. The closed-loop gain value is 20dB.A small serial resistor Rout is placed in order to remove HF oscillations.

The piezoelectric speaker used as load has the following characteristics:

Frequency range: 500Hz-20kHz
Capacitance: 140nF at 120Hz
Input voltage: 30vp-p max.

Figure 1: Electrical Schematic



#### **CHARACTERIZATION**

The dynamic behaviour is displayed through the two following figures :

- Frequency response at V<sub>CC</sub> = 3V (figure 2). This application is particularly stable within the range of the piezo (the gain is dropping by only 2.5dB).
- Output swing versus supply voltage: the pushpull configuration is theorically allowing a doubled output voltage amplitude versus V<sub>CC</sub>: the outputs on each side of the cell are rail to rail and phase opposite.

Figure 2: Frequency Response

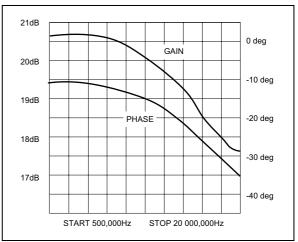


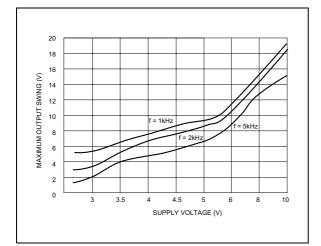
Figure 3 shows that this goal is highly dependant of the frequency; for example the total output swing available at 2kHz is recovered as followed:

■ V<sub>CC</sub> = 3V Out.vol.=3.4Vpp 57% of 6vpp theor. V<sub>CC</sub> = 4V 6.6Vpp 82% V<sub>CC</sub> = 5V 8.7Vpp 87% V<sub>CC</sub> = 8V 14.6Vpp 91%

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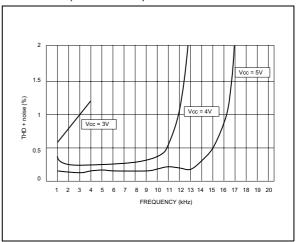
As a typical feature of any audio application, one may consider Total Harmonic Distorsion (THD) which is here considered with power supply as a parametric value (Figure 4).

Figure 3: Output Swing versus Supply Voltage



The piezo is then correctly driven with low voltage supply down to 4V

**Figure 4 :** Distorsion + Noise versus Frequency (Vo = 1Vrms)



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